#### TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

# 2 S C 5 2 5 9

## VHF~UHF BAND LOW NOISE AMPLIFIER APPLICATIONS

Low Noise Figure : NF = 1.7dB (f = 2GHz): Gain = 8.5dB (f = 2GHz)High Gain

### MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$v_{CBO}$	15	V
Collector-Emitter Voltage	$v_{CEO}$	7	V
Emitter-Base Voltage	$v_{\mathrm{EBO}}$	1.5	V
Collector Current	$I_{\mathbf{C}}$	15	mA
Base Current	$I_{\mathbf{B}}$	7	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	150	mW
Junction Temperature	$T_{j}$	125	°C
Storage Temperature Range	$T_{ m stg}$	-55~125	$^{\circ}\mathrm{C}$

**SYMBOL** 

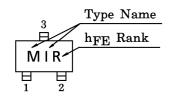
 $|S_{21e}|^2$  (1)

 $|S_{21e}|^2$  (2)

NF(1)

NF (2)

#### **MARKING**



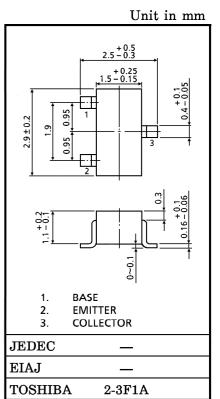
CHARACTERISTIC

Transition Frequency

Insertion Gain

Noise Figure

## MICROWAVE CHARACTERISTICS (Ta = 25°C)



Weight: 12mg							
TEST CONDITION	MIN.	TYP.	MAX.	UNIT			
$V_{CE} = 5V, I_{C} = 7mA$	9	12	_	GHz			
$V_{CE}=5V$ , $I_{C}=7mA$ , $f=1GHz$	11.5	14.5	_	dB			
$V_{CE}=5V$ , $I_{C}=7mA$ , $f=2GHz$	5.5	8.5	_	иь			

1.3

1.7

dB

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I <sub>CBO</sub>	$V_{CB} = 10V, I_{E} = 0$	_	_	1	$\mu$ A
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=1V, I_{C}=0$	_	_	1	$\mu$ A
DC Current Gain	hFE (Note 1)	$V_{\rm CE}$ =5V, $I_{\rm C}$ =7mA	50	_	160	_
Output Capacitance	$C_{ob}$	$V_{CB} = 5V, I_{E} = 0, f = 1MHz$	_	0.4	_	pF
Reverse Transfer Capacitance	$\mathrm{C_{re}}$	(Note 2)		0.3	0.7	pF

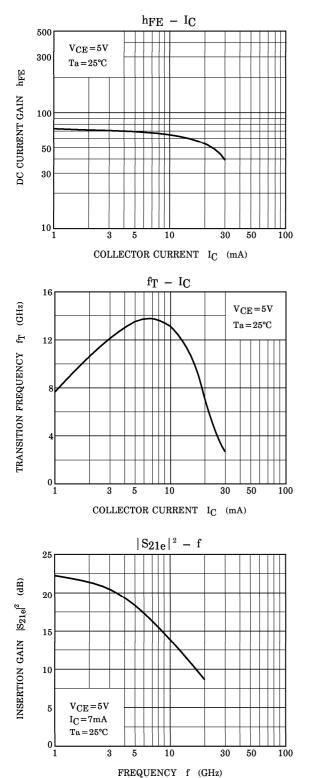
 $V_{CE} = 5V$ ,  $I_{C} = 3mA$ , f = 1GHz

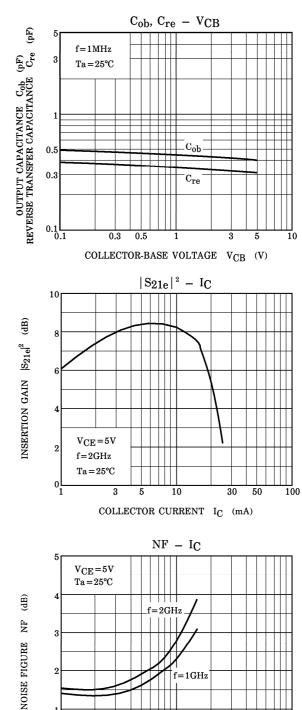
 $V_{CE} = 5V$ ,  $I_{C} = 3mA$ , f = 2GHz

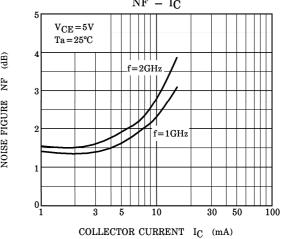
(Note 1): hFE Classification  $R:50\sim100$ ,  $O:80\sim160$ 

(Note 2):  $C_{re}$  is measured by 3 terminal method with capacitance bridge.

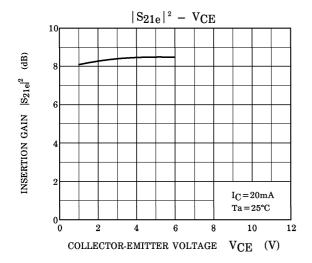
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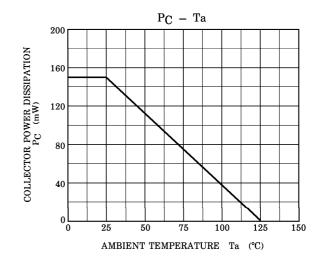






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